NSN 5961-01-178-3258

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-178-3258 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.290 inches **Overall Diameter:** 0.510 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 collector to emitter voltage/static/base open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 320.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 63.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No